

Scaling behavior of the ground-state antihydrogen yield as a function of positron density and temperature from classical-trajectory Monte Carlo simulations

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Antihydrogen production has reached such a level that precision spectroscopic measurements of its properties are within reach. In particular, the ground-state level population is of central interest for experiments aiming at antihydrogen spectroscopy. The positron density and temperature dependence of the ground-state yield is a result of the interplay between recombination, collisional, and radiative processes. Considering the fact that antihydrogen atoms with the principal quantum number $n = 15$ or lower quickly cascade down to the ground state within 1 ms, the number of such states is adopted as a measure of useful antihydrogen atoms. It has been found that the scaling behavior of the useful antihydrogen yield is different depending on the positron density and positron temperature.

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I. INTRODUCTION

Antihydrogen, the simplest antiatom consisting of a positron and an antiproton, is expected to provide one of the most stringent test grounds of *CPT* symmetry, the most fundamental symmetry in the standard model. For this purpose, its formation [1–3] and its trapping [4–6] have been the focus of several antimatter experiments in the last two decades. Very recently, the preparation of an antihydrogen beam for in-flight spectroscopy has been successfully demonstrated [7]. The goal of the experiments is to prepare ground-state antihydrogen for precision measurements. The sensitivity of these measurements usually depends on the ground-state level population.

Antihydrogen is produced by mixing together cold antiprotons and positrons. It is well known that the dominant formation mechanism is three-body recombination to Rydberg states, while the subsequent evolution of level population is governed by collisional (de)excitation and ionization. The list of the important processes is given in Table I. The positron temperature and density dependence of the rates of recombination and ionization or (de)excitation processes are different. The rates of these collisional processes and antihydrogen formation have been previously studied using classical-trajectory Monte Carlo (CTMC) methods [8–11]. The first detailed analysis of the three-body recombination rate in a strongly magnetized, cryogenic plasma was performed by Glinsky and O’Neil [8]. Robicheaux and Hanson [12] studied the three-body recombination rate and antihydrogen formation for positron temperature $4 \leq T_e \leq 16$ K and magnetic field strength $B = 3$ T and 5.4 T. Another study of antihydrogen formation was done by Jonsell *et al.* [13] for the conditions of the ATHENA experiment [2], using a positron temperature scale of $T_e = 15$ K and magnetic field strength of $B = 3$ T. A detailed study has been published by Bass and Dubin [11] using Monte Carlo simulations for antihydrogen formation

in cryogenic temperatures and strongly magnetized environments. In their work Bass and Dubin studied antihydrogen formation at low positron temperature and high magnetic field, and characterized such a regime with a magnetization parameter $\chi \equiv \bar{v}/b\Omega_c = 0.0018(T_e/4 \text{ K})^{3/2}/(B/6 \text{ T})$, where T_e is positron temperature, B magnetic field strength, \bar{v} positron thermal speed, b classical distance of closest approach, and Ω_c positron cyclotron frequency. The magnetization parameter explored in their work ranges from $\chi = 0$ (infinite magnetic field) to $\chi = 0.005$. The later value corresponds, e.g., to a combination of $T = 10$ K positron temperature and $B = 10$ T magnetic field strength.

However, in some of the more recent experiments the positron temperature may be higher than studied previously [7,14]. In this work we study the magnetization parameter range of $0.04 \leq \chi \leq 3.5$, consistently covering both strongly and weakly magnetized plasma conditions, unlike previous studies. The calculation contains three-body and radiative recombination, ionization and collisional (de)excitation, spontaneous and stimulated radiative processes.

This paper is organized as follows. In Sec. II the level population model is outlined. First the atomic population evolution equations are described, and then the computation of the various rates is discussed. In Sec. III the model is used to compute level populations for typical experimental plasma conditions. Finally, Sec. IV concludes our findings.

II. LEVEL POPULATION MODEL

A. Evolution of atomic populations

Antihydrogen is formed by mixing antiproton and positron plasmas. For the formation of bound states, two processes are responsible: radiative recombination and three-body recombination. However, after bound states are formed, many other processes can take place: collisional (de)excitation and ionization by positron impact, spontaneous radiative decay, and stimulated radiative transitions due to the presence of a

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TABLE I. Atomic scattering processes during antihydrogen production. A star (*) or two stars (**) denote two different quantum states.

| Process name | Process |
|---------------------------------|--|
| Three-body recombination | $\bar{p} + e^+ + e^+ \rightarrow \bar{H}^* + e^+$ |
| Radiative recombination | $\bar{p} + e^+ \rightarrow \bar{H}^* + h\nu$ |
| Collisional (de)excitation | $\bar{H}^* + e^+ \leftrightarrow \bar{H}^{**} + e^+$ |
| Collisional Ionization | $\bar{H}^* + e^+ \rightarrow \bar{p} + e^+ + e^+$ |
| Spontaneous radiative decay | $\bar{H}^{**} \rightarrow \bar{H}^* + h\nu$ |
| Stimulated radiative transition | $\bar{H}^* + h\nu \rightarrow \bar{H}^{**} (+2h\nu)$ |

finite-temperature blackbody radiation field. For a particular bound state $N(i)$ (where N is level population, i.e., number of atoms in bound state i , where i is any quantum number), the scattering processes either populate or depopulate a given state. Therefore the evolution of level population of each state and the loss of antiprotons over time can be described by a system of coupled differential equations. For the evolution of the level population of bound states (i running over the quantum numbers chosen),

$$\begin{aligned} \frac{dN(i)}{dt} = & [C_{rr}(i) + C_{\text{tbr}}(i)n_e]n_e N_p - C_{\text{ion}}(i)n_e N(i) \\ & + \sum_{j \neq i} [C_{\text{col}}(j,i)n_e + C_{\text{str}}(j,i)]N(j) \\ & - N(i) \sum_{j \neq i} [C_{\text{col}}(i,j)n_e + C_{\text{str}}(i,j)], \end{aligned} \quad (1)$$

while the number of bare antiprotons fulfills the relation given by

$$\frac{dN_p}{dt} = \sum_i (C_{\text{ion}}(i)n_e N(i) - [C_{rr}(i) + C_{\text{tbr}}(i)n_e]n_e N_p). \quad (2)$$

Here N_p is the number of antiprotons, n_e is the density of positrons, C_x denotes rate coefficients for atomic process, $C_{rr}(i)$ and $C_{\text{tbr}}(i)$ denote rate coefficients for radiative and three-body recombination to state i , respectively, $C_{\text{ion}}(i)$ denotes ionization by positron impact from bound state i , $C_{\text{col}}(i,j)$ denotes collisional excitation or deexcitation by positron impact from state i to state j , and $C_{\text{str}}(i,j)$ denotes spontaneous or stimulated transitions due to the presence of a radiation field.

The coupled set of differential equations is solved using the Bulirsch-Stoer method [15]. The dimensionality of the problem depends on the number of bound states used during computation. The initial conditions used for the system are a completely empty antihydrogen level population and a given number of antiprotons. During the evolution antihydrogen bound states are formed by filling the empty level population according to Eq. (1).

B. Computation of rates of atomic processes

The rate coefficient of an atomic scattering process depends on the energy distribution of the impact particle, $C = \int \sigma(E)f(E)v dE$, where $f(E)dE = 2\sqrt{E/\pi}(k_B T_e)^{-3/2} \exp(-E/k_B T_e)dE$ is the energy distribution function with positron temperature T_e , $\sigma(E)$ is the cross

section as a function of energy E , v is the velocity of the impact particle, and k_B is the Boltzmann constant. The rate coefficient can be computed by Monte Carlo methods, randomly sampling the energy distribution of the projectile (e^+), counting the occurrence of various final states, and scanning with the impact parameters used for the orbitals. The collision can be simulated by integrating the coupled Newton's equations of motion for the projectile and bound positron, and using a fixed antiproton position. In case of magnetic field given in a certain direction, the coordinates can be chosen such that the integration is done in a cylindrical system and the initial microcanonical ensemble distributions can be prepared accordingly [16]. From the computed rate of ionization the three-body recombination rate can be derived using the detailed balance principle and assuming thermodynamical equilibrium

$$C_{\text{tbr}}(i) = C_{\text{ion}}(i)g_i n_e \Lambda^3 e^{\frac{E(i)}{k_B T_e}}, \quad (3)$$

where $g_i = n_i^2$ is the statistical weight of state i with principal quantum number n_i , $\Lambda = h/\sqrt{2\pi m_e k_B T_e}$ is the thermal de Broglie wavelength of the positron, m_e is the positron mass, and $E(i)$ is the binding energy of state i . In the computation the detailed balance principle is also applied between the collisional excitation and de-excitation rates.

The radiative recombination rate is calculated as follows. For each n principal and l orbital quantum number, the radial part of the wave function is computed using a finite difference method based on the Numerov algorithm. Then the energy normalized continuum state for angular momenta $l-1$ and $l+1$ is computed at energy E using the same finite difference algorithm. The recombination rate to a specific n, l in atomic units is then

$$\begin{aligned} \langle \sigma_{rr} v \rangle_{n,l} = & \left(\frac{2\pi}{T_e} \right)^{3/2} \left(\frac{4}{3} \right) \alpha^3 \int dE (E - E_{nl})^3 \\ & \times e^{-\frac{E}{k_B T_e}} [(l-1)D_{E,l-1}^2 + lD_{E,l+1}^2], \end{aligned} \quad (4)$$

where α is the fine structure constant, and $D_{E,l}$ denotes dipole matrix elements calculated for energy E and orbital quantum number l . The dipole matrix elements are computed using numerical integration over the radial coordinate r and cross-checked by recomputing using a length and velocity gauge.

Spontaneous radiative decay rates are calculated from Einstein A-coefficients for hydrogen orbitals. Stimulated transition rates for an external blackbody radiation field, with temperature T_r , are added using the radiative transition rates as

$$C_{em}(i,j) = C_{\text{rad}}(i,j) \left[1 + \frac{1}{\exp(E_{ij}/k_B T_r) - 1} \right], \quad i > j, \quad (5)$$

$$C_{\text{abs}}(i,j) = C_{\text{rad}}(j,i) \frac{1}{\exp(E_{ij}/k_B T_r) - 1}, \quad i < j, \quad (6)$$

where $C_{\text{rad}}(i,j)$ is the spontaneous radiative transition rate, $C_{em}(i,j)$ and $C_{\text{abs}}(i,j)$ are the stimulated emission and absorption rates between states i and j , and $E_{ij} = |E(i) - E(j)|$ are the binding energy differences.

Rate coefficients have been calculated for various positron temperatures and magnetic field strengths. For zero magnetic field our calculation agrees with result of Pohl *et al.* [10].

Thermodynamical equilibrium detailed balance was applied between the rates of direct and indirect processes for collisional (de)excitation, such that the following relation is established:

$$\frac{C(n_i \rightarrow n_f)}{C(n_f \rightarrow n_i)} = \frac{n_f^2}{n_i^2} e^{\frac{E(f)-E(i)}{k_B T_e}}, \quad (7)$$

where $C(n_i \rightarrow n_f)$ denotes rate of a process from initial state n_i to final state n_f .

III. DISCUSSION

A. Level population evolution for experimental conditions

The coupled system of differential equations is solved, for example, 150 bound states, corresponding to principal quantum numbers $n_i = 1 \dots 150$, a number chosen sufficiently large to represent a thermal equilibrium level population for highly excited Rydberg states. The initial conditions for the solution are an empty level population for the bound states of antihydrogens, $N_p = 10^6$ antiprotons, a positron density of $n_e = 10^{14} \text{ m}^{-3}$, a positron temperature of $T_e = 50 \text{ K}$, and a magnetic field strength of $B = 2 \text{ T}$. A typical result is shown in Fig. 1 for a range of evolution times $10 \mu\text{s}$ (circle), $20 \mu\text{s}$ (square), and $50 \mu\text{s}$ (triangle). Also, the thermal equilibrium distribution of bound-state population, given by the Saha-Boltzmann relation, is shown for the same temperature of $T_e = 50 \text{ K}$ (solid line):

$$N_{th}(i) = N_p n_e n_i^2 \Lambda^3 e^{\frac{E(i)}{k_B T_e}}. \quad (8)$$

A typical experimental time scale for evolution is $10 \mu\text{s}$ (empty circles in Fig. 1), which is the average time an antiproton spends in the positron plasma. This time scale is set by the typical thermal speed of antiprotons in these experiments at $T_e = 300 \text{ K}$ temperature and the typical length scale of the positron plasma of $L_{e^+} \simeq 20 \text{ mm}$ [7]. For highly excited Rydberg states (principal quantum number, $n_i \geq 50$), after a few μs of evolution time, a thermal equilibrium is established, while for deeper states the system does not reach thermal equilibrium. The rates of the various processes

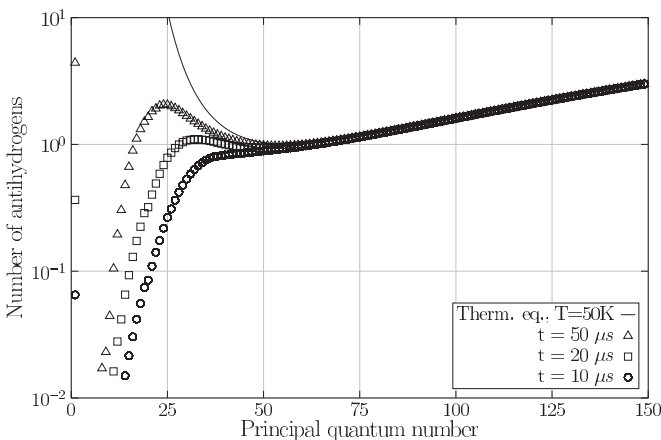


FIG. 1. Antihydrogen bound-state level population distribution after evolution of $10 \mu\text{s}$ (circle), $20 \mu\text{s}$ (square), and $50 \mu\text{s}$ (triangle) and the thermal equilibrium level population distribution (solid line) for positron temperature of $T_e = 50 \text{ K}$ and positron density $n_e = 10^{14} \text{ m}^{-3}$.

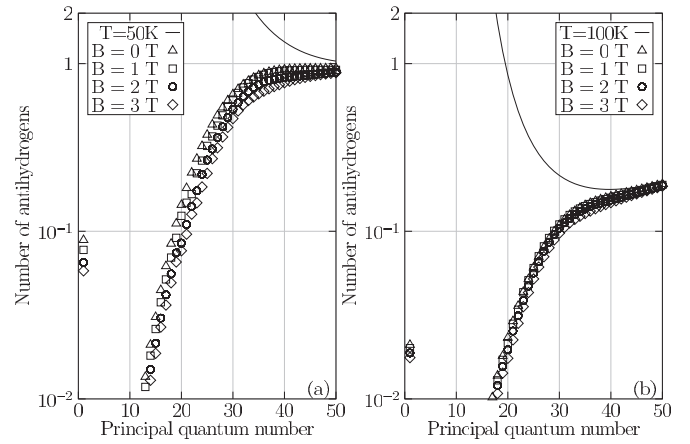


FIG. 2. Antihydrogen bound-state level population distribution after evolution of $10 \mu\text{s}$ for various magnetic field strengths $0 \leq B \leq 3 \text{ T}$, and the thermal equilibrium level population distribution (solid line) for positron temperatures $T_e = 50 \text{ K}$ (a) and $T_e = 100 \text{ K}$ (b) and positron density $n_e = 10^{14} \text{ m}^{-3}$.

shaping the level population distribution change differently as a function of the principal quantum number, n_i : radiative decay rates decrease rapidly with n_i , positron-Rydberg atom collision rates increase with n_i , capture by radiative recombination favors low n_i , while capture by three-body recombination favors high n_i . There is a characteristic excited-state level below which the level population is depleted, eventually reaching a point where the spontaneous radiative decay rates dominate and the ionization rate becomes very low.

In Fig. 2 the impact of variation of magnetic field on the level population is shown for $T_e = 50 \text{ K}$ and $T_e = 100 \text{ K}$ positron temperatures. While at $T_e = 50 \text{ K}$ the ground-state level population is reduced by $\sim 50\%$ with increasing magnetic field strength, and already at $T_e = 100 \text{ K}$ the level population does not reduce significantly even at high magnetic field strengths. In the following discussion the magnetic field strength is fixed at $B = 2 \text{ T}$.

B. Positron plasma parameter scan

The aim of this work is to investigate the evolution and scaling behavior of the ground-state level population of antihydrogen atoms with a wide range of positron plasma parameters. Given that the evolution is governed by a large set of coupled differential equations, in which the population of a particular quantum state could receive a contribution from any other quantum state, the scaling behavior of the ground-state level population cannot be calculated with a simple formula. For each positron plasma density and temperature the conditions at the beginning and during evolution are different; therefore for each case the evolution will also take a different path. In order to study the effect of different plasma conditions on the ground-state level population, a parameter scan of positron density and temperature has been performed in the range $10^{14} \leq n_e \leq 10^{16} \text{ m}^{-3}$ and $20 \leq T_e \leq 300 \text{ K}$. A new level population simulation was carried out for each temperature and density point, using $N_p = 10^6$ initial antiprotons, with a fixed evolution time of $10 \mu\text{s}$.

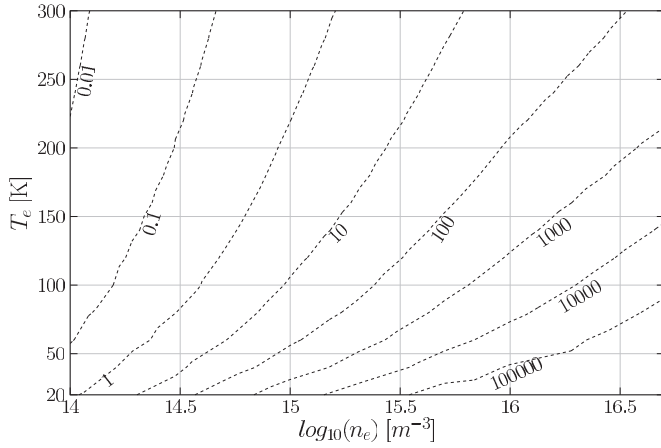


FIG. 3. Contour plot of the number of ground-state antihydrogen atoms for various positron temperatures (vertical axis) and density values (horizontal axis).

For experiments attempting ground-state antihydrogen spectroscopy, the figure of merit is the number of ground-state antihydrogen atoms with respect to plasma parameters. Experimentally there is usually a defined trapping time or a flight time after which the measurements are performed. During this time some fraction of the excited states will decay and populate the ground state. Thus the total ground-state yield may be defined as an integral of the level population from $n = 1$ to some upper principal quantum number, which depends on the particular experiment. As a possible upper limit in the current work the $n = 15$ level is used because the lifetime of direct transition from this level to ground state is within an order of a millisecond, a typical time scale for an in-flight type of experiment.

Figure 3 illustrates the result of the plasma parameter scan for ground-state level population scaling behavior, represented as a contour plot where each contour line corresponds to the same ground-state antihydrogen yield. It is generally expected that at low positron temperatures and high densities the antihydrogen yield is larger than at high temperatures and low densities. However, the rate of increase in the number of antihydrogens does not follow any simple scaling law. For example, at $T_e = 40$ K, for an order-of-magnitude increase in positron density the antihydrogen number increases by 3 orders of magnitude. However, at $T_e = 300$ K the number of antihydrogens increases only 1–2 orders of magnitude for the same increase of positron density. These findings confirm that the evolution of level population of antihydrogen atoms strongly depends on the positron plasma conditions at the start and during the evolution.

Once the antihydrogen leaves the positron plasma, the atoms will no longer undergo collisional or recombination processes. Only spontaneous radiative decay and blackbody radiation govern the level population rate equations. The level population evolution during a 1-ms flight has been simulated by integrating the same rate equations [Eq. (1)] but considering only the radiative processes and setting the initial value of the level population simulation according to the 10- μ s simulation result shown in Fig. 3. The result is shown in Fig. 4. The general trends for different positron density scaling across the

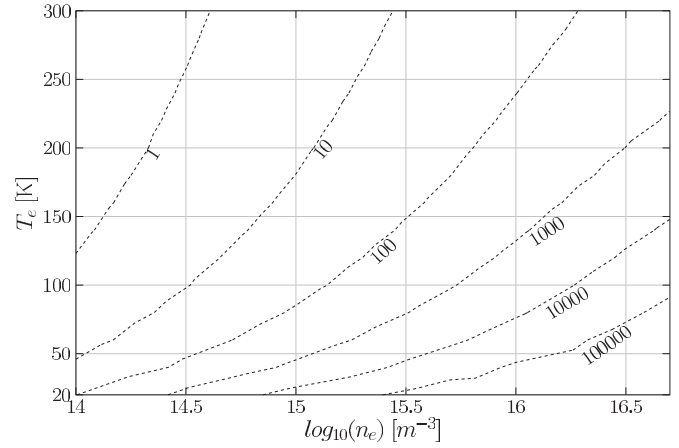


FIG. 4. Contour plot of the number of ground-state antihydrogen atoms for various positron temperatures (vertical axis) and density values (horizontal axis) after 10 μ s interaction and 1 ms of flight.

temperature range remains, but the scaling behavior seen in Fig. 3 is somewhat reduced by the radiative processes. At low temperatures an order-of-magnitude increase in positron density yields an approximately 2 orders of magnitude increase in ground-state atoms, while at high temperatures the number of ground-state atoms increases only 1 order of magnitude. However, at very high positron density, radiative decay does not seem to significantly impact the ground-state atom yield because almost all antihydrogen atoms are in $n_i \leq 15$ states.

The power-law scaling dependence of the number of ground-state antihydrogen atoms, $N(1)$, on positron temperature and density is shown in Fig. 5 for 10 μ s of plasma interaction and in Fig. 6 for an additional 1 ms of flight. Also, in Figs. 5 and 6, the expected scaling behavior is shown for three-body recombination (solid line), $R_{\text{ibr}} \propto n_e^2 T_e^{-4.5}$, as well as a lower limit scaling which is fitted to the shape dependence found in this work (dashed line).

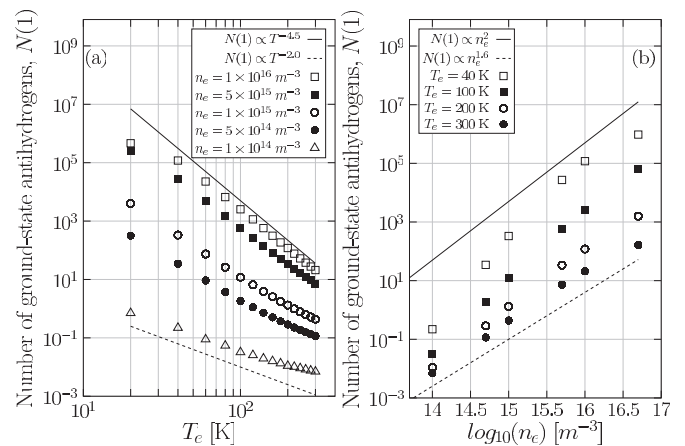


FIG. 5. Dependence of ground-state antihydrogen atoms on positron temperature (a) and density (b) for various positron density and temperature values (respectively) after 10 μ s of mixing. The $\propto n_e^2 T_e^{-4.5}$ (solid line) and $\propto n_e^{1.6} T_e^{-2.0}$ (dashed line) scaling behaviors are indicated for reference.

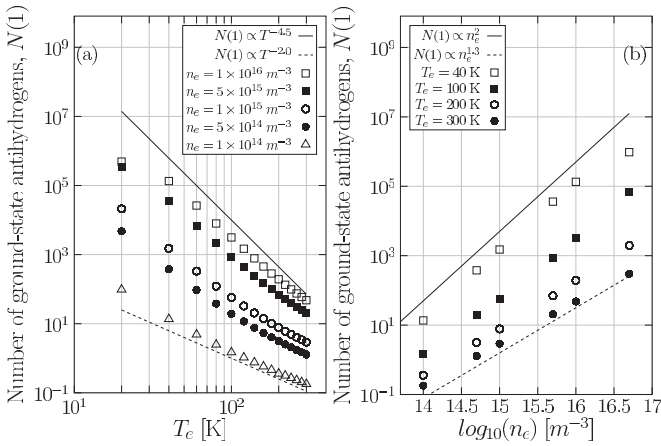


FIG. 6. Dependence of ground-state antihydrogen atoms on positron temperature (a) and density (b) for various positron density and temperature values (respectively) after 1 ms of flight. The $\propto n_e^2 T_e^{-4.5}$ (solid line) and $\propto n_e^{1.3} T_e^{-2.0}$ (dashed line) scaling behaviors are indicated for reference.

In the case of the 10- μ s interaction (Fig. 5) at, e.g., $T_e = 40$ K, the ground-state antihydrogen atom number seems to increase with positron density as $N(1) \propto n_e^{2.5}$. However, at room temperature the positron density dependence drops to $N(1) \propto n_e^{1.6}$. At the same time the temperature dependence seems to deviate most from pure three-body-like behavior at $n_e = 10^{14} m^{-3}$ positron density, showing a positron temperature dependence $N(1) \propto T_e^{-2.0}$. While at positron density $n_e = 10^{16} m^{-3}$ the temperature dependence becomes $N(1) \propto T_e^{-4.2}$. The behavior of the power-law scaling dependence suggests that at low positron temperature and high positron density the three-body recombination dominates the level population evolution, while at high positron temperature and low positron density collisional (de)excitation also becomes important during the evolution. In between these plasma conditions there is a transition region where the three-body recombination competes with the collisional deexcitation and the power-law scaling behavior of the ground-state level population deviates from that of both of these processes.

In case of an additional 1 ms of flight (Fig. 6), the deviations from pure three-body recombination are similar in nature. The behavior becomes closest to pure three-body recombination at low positron temperatures and high densities, while at higher temperatures or lower densities, the dependencies on the density and temperature are both weaker.

It is interesting to note also that there is significant increase in the number of ground-state antihydrogen atoms at $n_e = 10^{14} m^{-3}$ positron density. Both with and without 1 ms of flight, $N(1)$ increases around 2 orders of magnitude when the positron temperature is reduced from $T_e = 300$ K to $T_e = 20$ K.

As a cross-check of our findings, in order to see which process dominates the evolution to the ground state, we have performed the same parameter scan but turned off either radiative recombination or the collisional (de)excitation and ionization processes. When radiative recombination is removed from the list of processes, the impact on the contour plot in comparison with Fig. 3 is almost negligible. However, when all collisional processes are removed, the ground-state

yield is reduced such that only one ground-state atom is formed even at high positron densities ($n_e = 10^{16} m^{-3}$). This behavior confirms that the evolution is an interplay of collisional (de)excitation and three-body recombination, with different relative dominance in various plasma conditions.

The simulation results indicate that the number of antihydrogen atoms determined experimentally does not follow simple power-law scaling. For example, our simulation predicts that a measurement of the ground-state antihydrogen atom yield as a function of the positron plasma temperature at a positron plasma density $n_e \simeq 10^{14} m^{-3}$ would show a weaker power-law scaling behavior than that of three-body recombination. It is noted that the positron temperature dependence of antihydrogen formation was measured at positron density $n_e \simeq 10^{14} m^{-3}$, and an observed scaling behavior of $T_e^{-1.1 \pm 0.5}$ was reported [17] by the ATHENA Collaboration, which is consistent with the direction of our prediction qualitatively.

IV. CONCLUSION

In this work ground-state antihydrogen formation and scaling behavior was studied during mixing of antiprotons and positrons using recent and potential experimental positron plasma conditions. The positron plasma magnetization parameter range $0.04 \leq \chi \leq 3.5$ was explored using CTMC simulation combined with level population evolution. It was found that the scaling of the ground-state antihydrogen atoms does not follow a simple power-law behavior but depends on the particular positron plasma conditions. The positron plasma density and temperature determine the relative dominance between collisional (de)excitation and three-body recombination during the evolution. The results show that the ground-state antihydrogen yield deviates significantly from pure three-body recombination behavior at higher positron temperature and lower density, and suggests that in this plasma condition collisional deexcitation becomes more important for ground-state population. In the case of low positron temperature and high density the three-body recombination behavior is recovered, suggesting the importance of the three-body process over collisional deexcitation to populate the ground-state level in this positron plasma condition. In the case of an additional 1-ms flight of the antihydrogen atoms, without recombination or collisions, the qualitative scaling behavior remains similar but shows weaker dependence on positron density and temperature.

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